TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

### TC74AC04P,TC74AC04F,TC74AC04FN,TC74AC04FT

#### Hex Inverter

The TC74AC04 is an advanced high speed CMOS INVERTER fabricated with silicon gate and double-layer metal wiring C2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

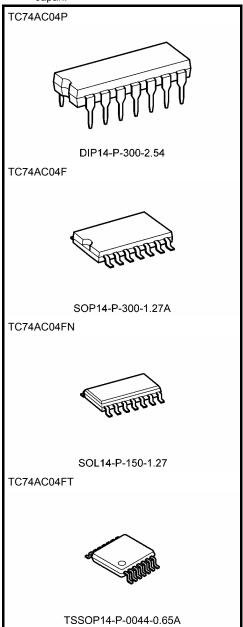
The internal circuit is composed of 3 stages including buffer output, which provide high noise immunity and stable output.

All inputs are equipped with protection circuits against satic discharge or transient excess voltage.

#### **Features**

- High speed:  $t_{pd} = 3.2 \text{ ns (typ.)}$  at  $V_{CC} = 5 \text{ V}$
- Low power dissipation:  $I_{CC} = 4 \mu A$  (max) at  $T_a = 25$ °C
- High noise immunity: V<sub>NIH</sub> = V<sub>NIL</sub> = 28% V<sub>CC</sub> (min)
- Symmetrical output impedance:  $|I_{OH}| = I_{OL} = 24$  mA (min) Capability of driving 50  $\Omega$  transmission lines.
- Balanced propagation delays:  $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range:  $V_{CC \text{ (opr)}} = 2 \text{ to } 5.5 \text{ V}$
- Pin and function compatible with 74F04

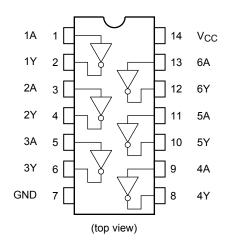
Note: xxxFN (JEDEC SOP) is not available in Japan.



Weight

DIP14-P-300-2.54 : 0.96 g (typ.) SOP14-P-300-1.27A : 0.18 g (typ.) SOL14-P-150-1.27 : 0.12 g (typ.) TSSOP14-P-0044-0.65A : 0.06 g (typ.)

### **Pin Assignment**



#### **IEC Logic Symbol**

1A — (1)	1	( <u>2)</u> 1Y
2A(3)		(4) 2Y
3A(5)		(6) 3Y
4A — (9)		(8) 4Y
5A (11)		(10) 5Y
6A <u>(13)</u>		(12) 6Y

#### **Truth Table**

Α	Υ
L	Н
Н	L

#### **Absolute Maximum Ratings (Note 1)**

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	−0.5 to 7.0	V
DC input voltage	V <sub>IN</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
DC output voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	l <sub>IK</sub>	±20	mA
Output diode current	lok	±50	mA
DC output current	lout	±50	mA
DC V <sub>CC</sub> /ground current	Icc	±150	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP/TSSOP)	mW
Storage temperature	T <sub>stg</sub>	−65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C should be applied up to 300 mW.



# **Operating Ranges (Note)**

Characteristics	Symbol	Rating	Unit	
Supply voltage	$V_{CC}$	2.0 to 5.5	V	
Input voltage	V <sub>IN</sub>	0 to V <sub>CC</sub>	V	
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	V	
Operating temperature	T <sub>opr</sub>	−40 to 85	°C	
Input rise and fall time	dt/dV	0 to 100 (V <sub>CC</sub> = 3.3 ± 0.3 V)	ns/V	
input rise and rail time	αναν	0 to 20 ( $V_{CC} = 5 \pm 0.5 \text{ V}$ )	113/V	

Note: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either VCC or GND.

#### **Electrical Characteristics**

#### **DC Characteristics**

Characteristics	Symbol		Test Condition		Ta = 25°C			Ta = −40 to 85°C		Unit	
Sharacteristics Symb	Symbol				V <sub>C</sub> C (V)	Min	Тур.	Max	Min	Max	Offic
		_		2.0	1.50	_	_	1.50	_		
High-level input voltage	V <sub>IH</sub>			3.0	2.10	_	_	2.10	_	V	
					5.5	3.85	_	_	3.85	_	
					2.0	_	_	0.50	_	0.50	
Low-level input voltage	$V_{IL}$		_		3.0	_	_	0.90	_	0.90	V
					5.5	_	_	1.65	_	1.65	
	Vон	V <sub>IN</sub> = V <sub>IL</sub>			2.0	1.9	2.0	_	1.9	_	
			I <sub>OH</sub> = -50 μA		3.0	2.9	3.0	_	2.9	_	
High-level output					4.5	4.4	4.5	_	4.4	_	V
voltage			I <sub>OH</sub> = -4 mA		3.0	2.58	_	_	2.48	_	V
			I <sub>OH</sub> = −24 mA		4.5	3.94	_	_	3.80	_	
			I <sub>OH</sub> = −75 mA	(Note)	5.5	_	_	_	3.85	_	
	VoL	V <sub>IN</sub> = V <sub>IH</sub>			2.0	_	0.0	0.1	_	0.1	
			I <sub>OL</sub> = 50 μA		3.0	_	0.0	0.1	_	0.1	
Low-level output					4.5	_	0.0	0.1	_	0.1	V
voltage			I <sub>OL</sub> = 12 mA		3.0	_	_	0.36	_	0.44	·
			I <sub>OL</sub> = 24 mA		4.5	_	_	0.36	_	0.44	
			I <sub>OL</sub> = 75 mA	(Note)	5.5	_	_	_	_	1.65	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	_	±0.1	_	±1.0	μΑ	
Quiescent supply current	Icc	V <sub>IN</sub> = V <sub>C</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	_	4.0	_	40.0	μΑ

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Note: This spec indicates the capability of driving 50  $\Omega$  transmission lines.

One output should be tested at a time for a 10 ms maximum duration.



### AC Characteristics (C<sub>L</sub> = 50 pF, R<sub>L</sub> = 500 $\Omega$ , input: $t_r$ = $t_f$ = 3 ns)

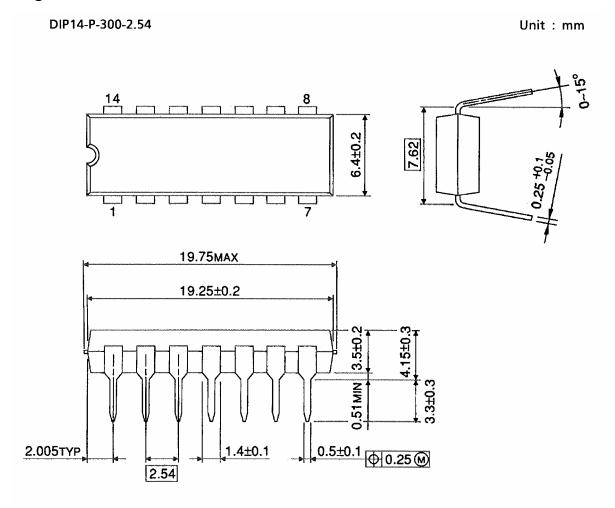
Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
	.,		V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	
Propagation delay time	t <sub>pLH</sub>		$3.3 \pm 0.3$	_	5.7	9.8	1.0	11.2	no
	t <sub>pHL</sub>	_	5.0 ± 0.5	_	4.3	6.6	1.0	7.5	ns
Input capacitance	C <sub>IN</sub>	_		_	5	10	_	10	pF
Power dissipation capacitance	C <sub>PD</sub>		(Note)	ı	20	-	ı	_	pF

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6 (per gate)$ 

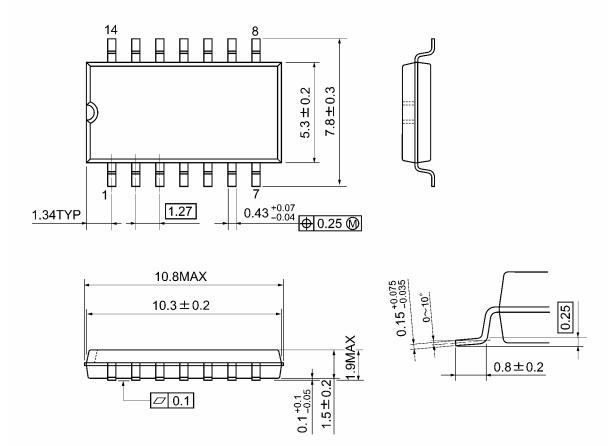
# **Package Dimensions**



Weight: 0.96 g (typ.)

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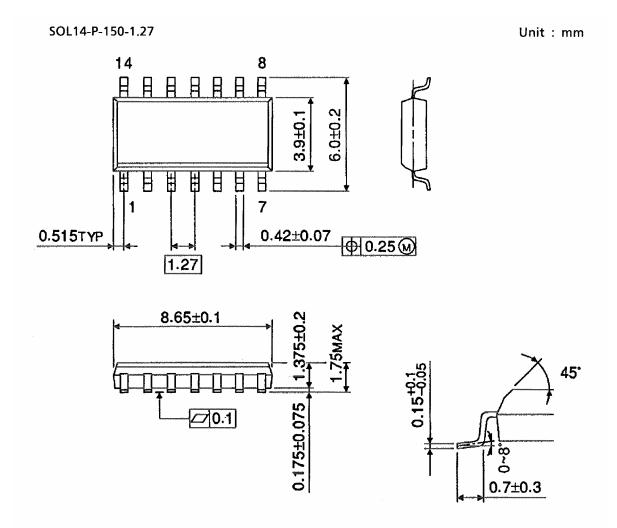
SOP14-P-300-1.27A Unit: mm



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Weight: 0.18 g (typ.)

# **Package Dimensions (Note)**

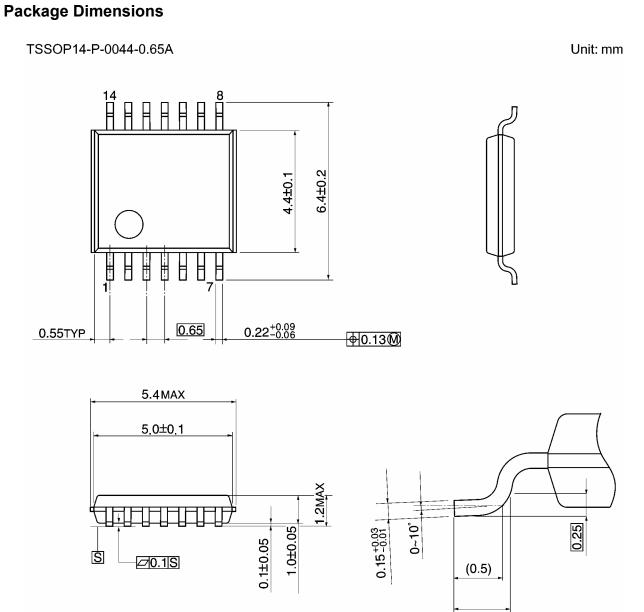


Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

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Weight: 0.06 g (typ.)

0.45~0.75

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